



PESD3V3C1BSF

Ultra low capacitance bidirectional ESD protection diode

26 June 2015

Product data sheet

1. General description

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode, part of the TrEOS Protection family. This device is housed in a DSN0603-2 (SOD962) leadless ultra small Surface-Mounted Device (SMD) package. The TrEOS Protection family is optimized for safeguarding very sensitive high-speed interfaces against ESD pulses with a high level of robustness.

2. Features and benefits

- Bidirectional ESD protection of one line
- Extremely low diode capacitance $C_d = 0.2$ pF
- ESD protection up to ± 20 kV according to IEC 61000-4-2
- Ultra small SMD package

3. Applications

ESD and surge protection for:

- ultra high-speed datalines
- very sensitive interface lines
- generic interface lines

in portable electronics, communication, consumer and computing devices.

4. Quick reference data


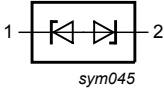
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage	$T_{amb} = 25$ °C	-	-	3.3	V
C_d	diode capacitance	$f = 1$ MHz; $V_R = 0$ V; $T_{amb} = 25$ °C	-	0.2	0.25	pF



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)	 <p>Transparent top view</p> <p>DSN0603-2 (SOD962-2)</p>	 <p><i>sym045</i></p>
2	K2	cathode (diode 2)		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD3V3C1BSF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2

7. Marking

Table 4. Marking codes

Type number	Marking code
PESD3V3C1BSF	P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
I_{PPM}	rated peak pulse current	$t_p = 8/20 \mu s$	[1]	-	9	A
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			-40	125	°C
T_{stg}	storage temperature			-65	150	°C
ESD maximum ratings						
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[2]	-	20	kV
		IEC 61000-4-2; air discharge	[2]	-	20	kV

[1] According to IEC 61000-4-5 and IEC 61643-321.

[2] Device stressed with ten non-repetitive ESD pulses.

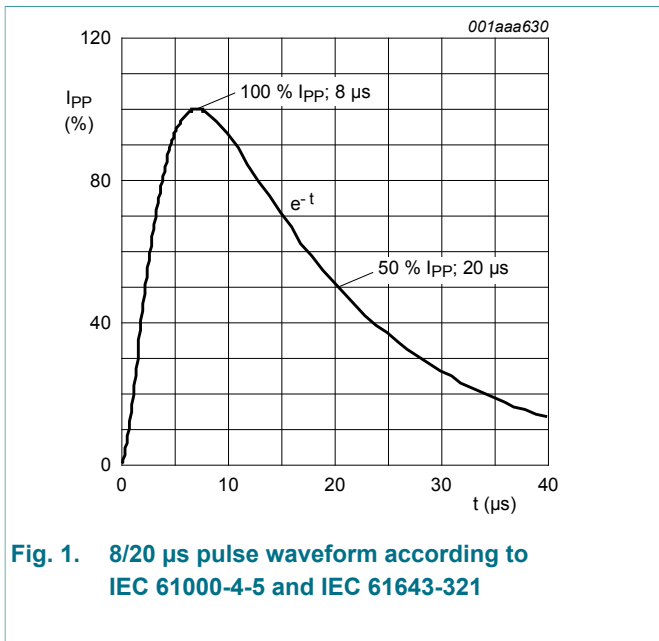


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

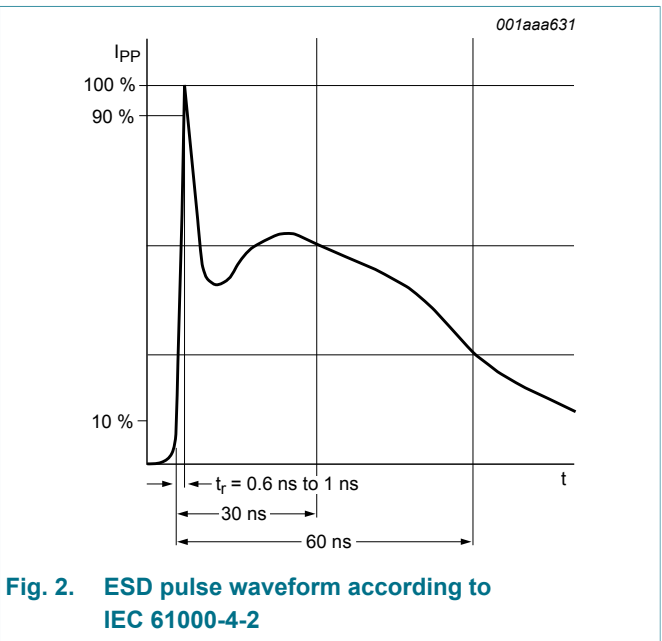


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage	$T_{amb} = 25\text{ }^{\circ}\text{C}$	-	-	3.3	V
I_{RM}	reverse leakage current	$V_{RWM} = 3.3\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	-	1	50	nA
V_{BR}	breakdown voltage	$I_R = 1\text{ mA}; T_{amb} = 25\text{ }^{\circ}\text{C}$	6	10	-	V
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 0\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	-	0.2	0.25	pF
		$f = 2.5\text{ GHz}; V_R = 0\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	-	0.2	-	pF
V_{CL}	clamping voltage	$I_{PPM} = 9\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}; t_p = 8/20\text{ }\mu\text{s}$	[1]	-	5.5	V
V_{CL}	clamping voltage	$I_{PP} = 8\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}; t_p = \text{TLP}$	[2]	-	4.6	V
		$I_{PP} = 16\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}; t_p = \text{TLP}$	[2]	-	6.5	V
R_{dyn}	dynamic resistance	$I_R = 10\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}$	[2]	-	0.23	Ω

[1] According to IEC 61000-4-5 and IEC 61643-321.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) $t_p = 100\text{ ns}$; square pulse; ANSI / ESD STM5.5.1-2008.

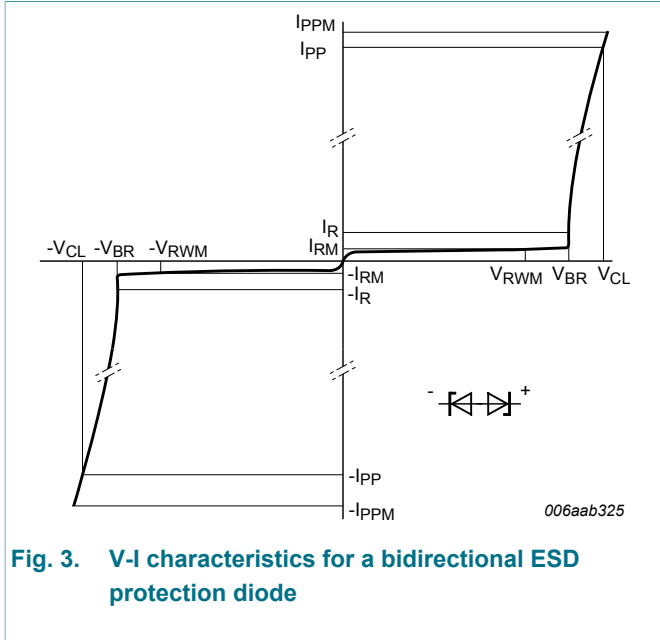


Fig. 3. V-I characteristics for a bidirectional ESD protection diode

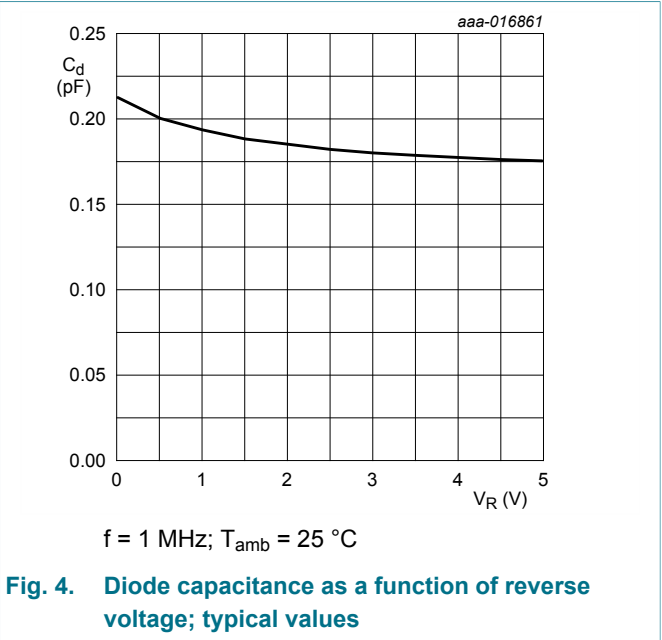


Fig. 4. Diode capacitance as a function of reverse voltage; typical values

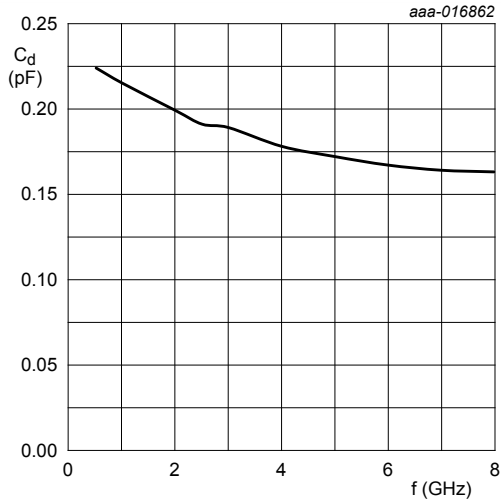


Fig. 5. Diode capacitance as a function of frequency; typical values

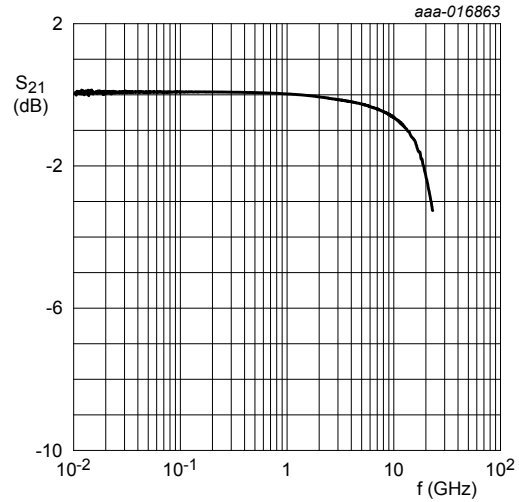
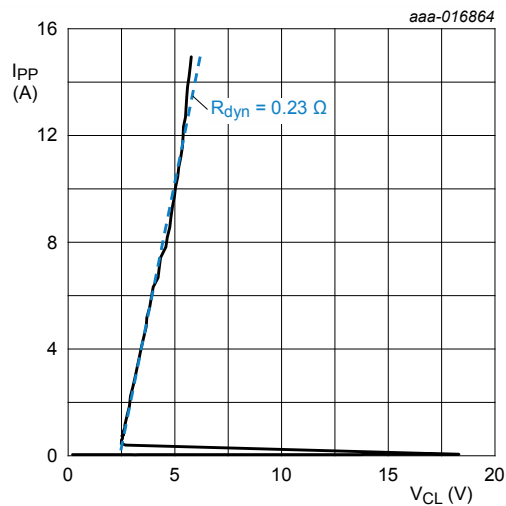
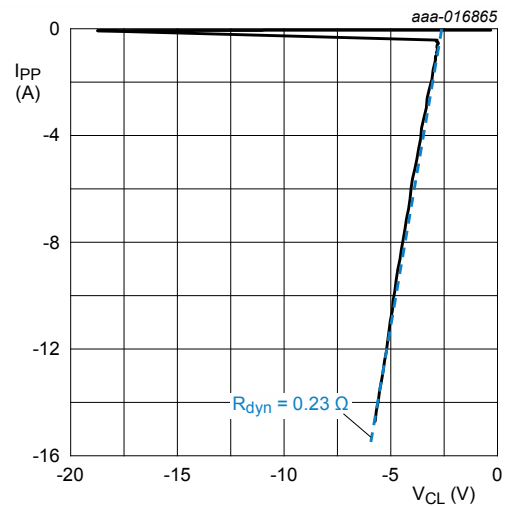


Fig. 6. Insertion loss; typical values



$t_p = 100$ ns; Transmission Line Pulse (TLP)

Fig. 7. Dynamic resistance with positive clamping voltage



$t_p = 100$ ns; Transmission Line Pulse (TLP)

Fig. 8. Dynamic resistance with negative clamping voltage

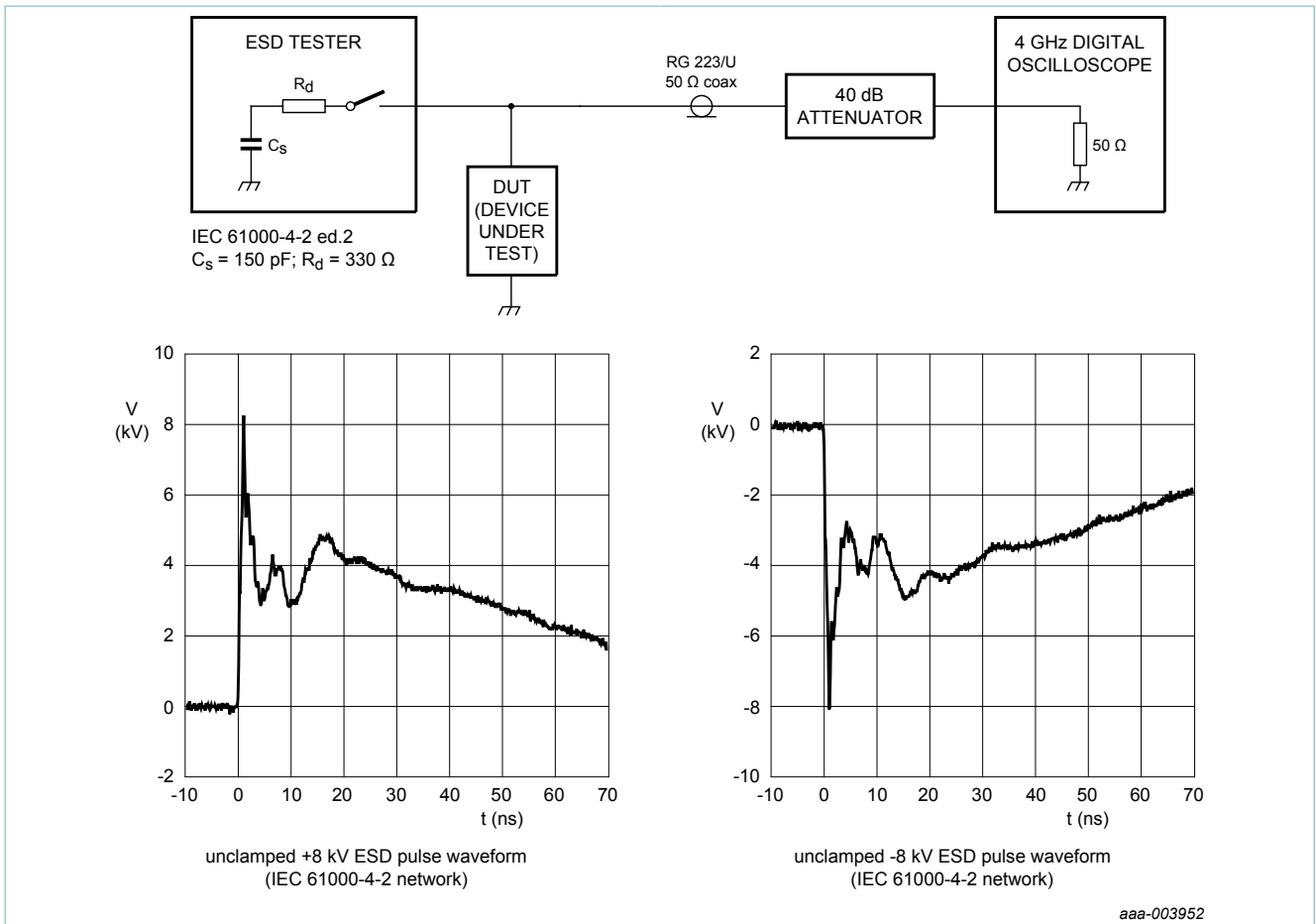


Fig. 9. ESD clamping test setup and waveforms

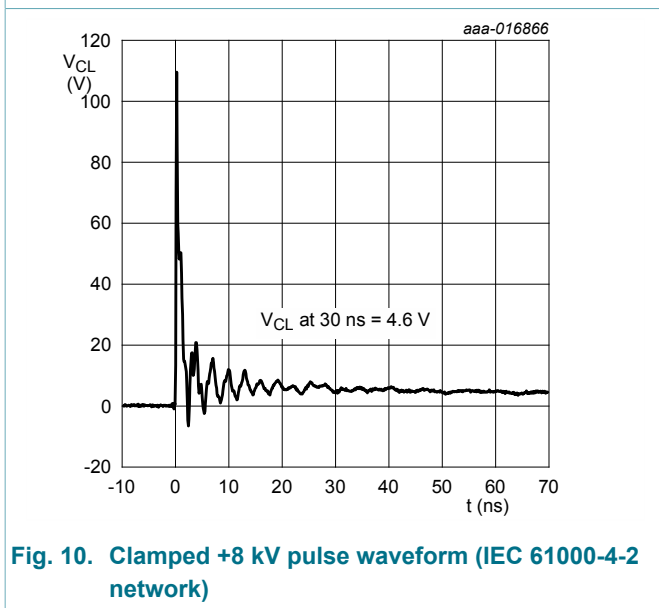


Fig. 10. Clamped +8 kV pulse waveform (IEC 61000-4-2 network)

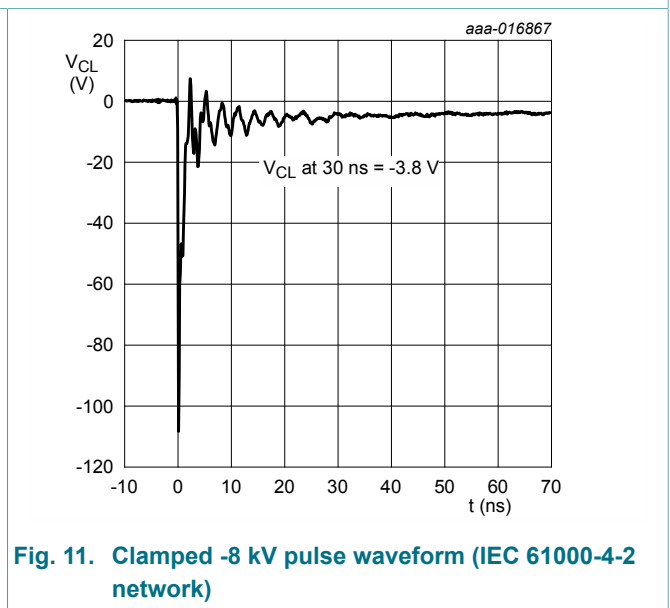


Fig. 11. Clamped -8 kV pulse waveform (IEC 61000-4-2 network)

10. Application information

The device is designed for the protection of one bidirectional data line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both positive and negative with respect to ground. The device is not designed to be used on lines connected to a DC supply.

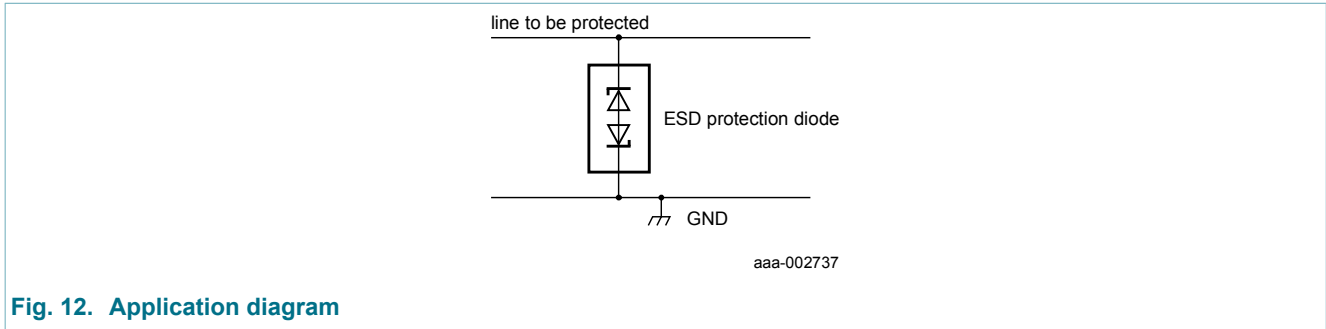


Fig. 12. Application diagram

Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

1. Place the device as close to the input terminal or connector as possible.
2. Minimize the path length between the device and the protected line.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

11. Package outline

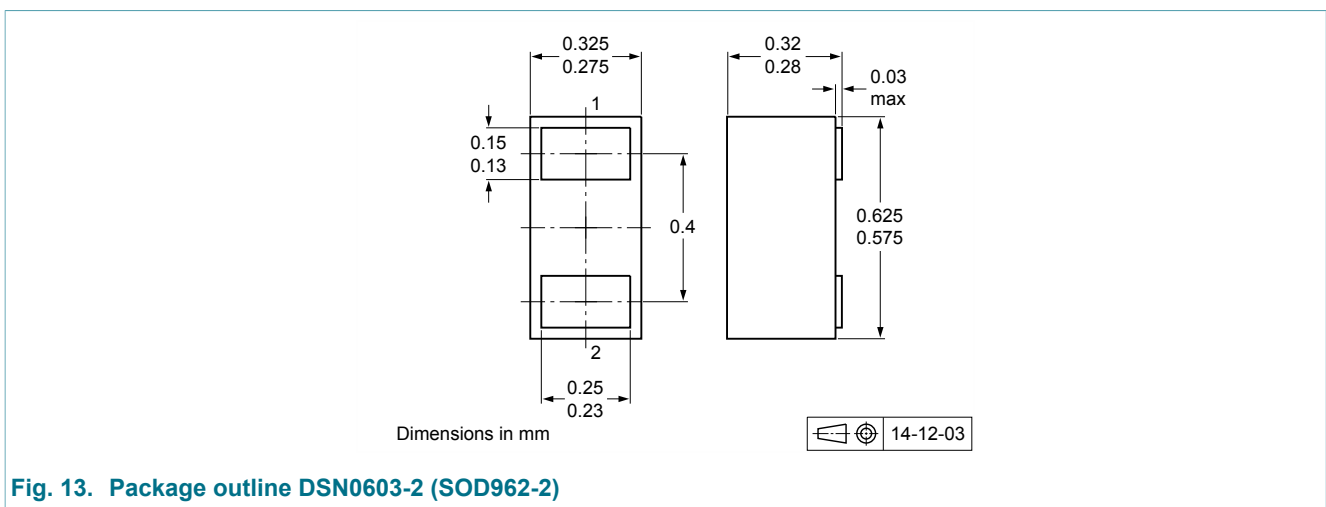


Fig. 13. Package outline DSN0603-2 (SOD962-2)

12. Soldering

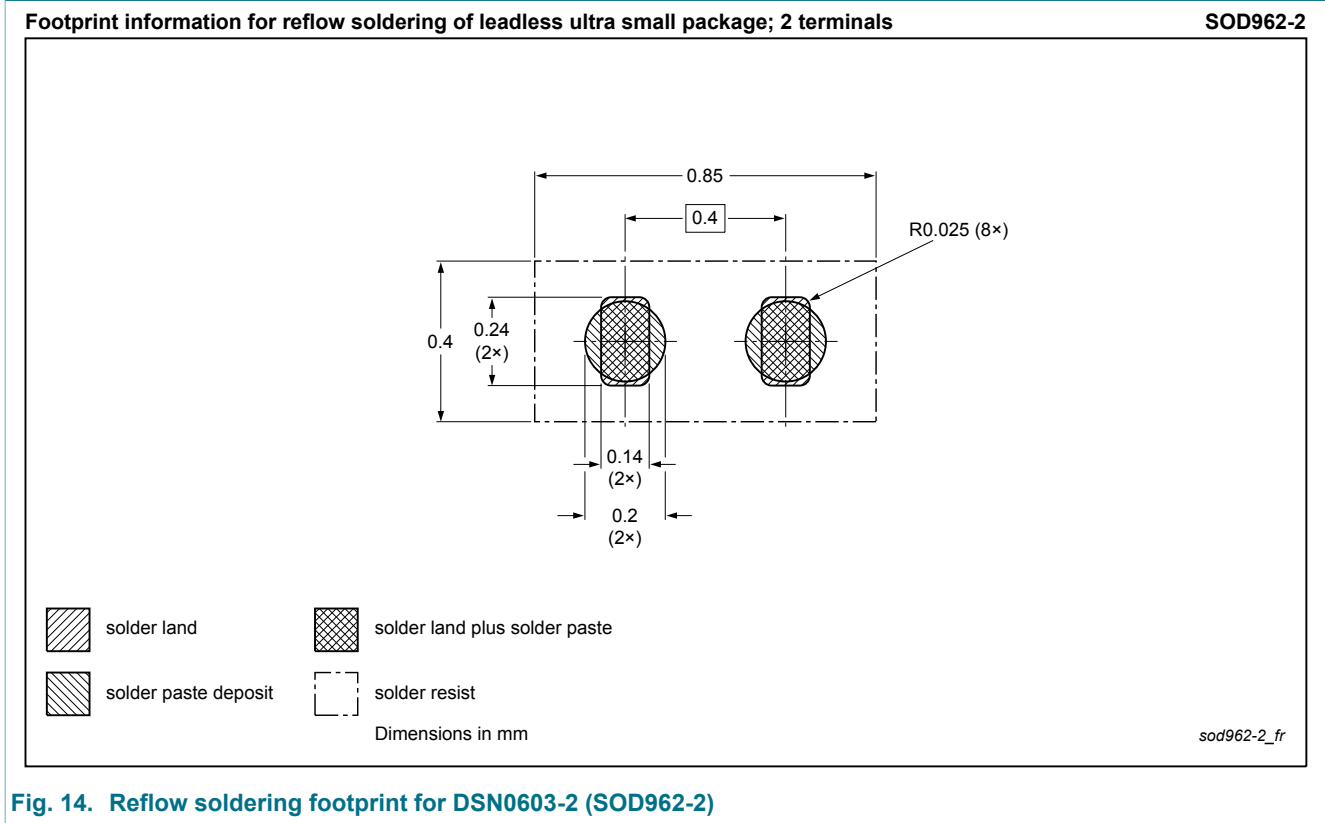


Fig. 14. Reflow soldering footprint for DSN0603-2 (SOD962-2)

13. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD3V3C1BSF v.1	20150626	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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